

Sub C1
7. (amended) A device according to any one of Claims 1, wherein the substrate comprises polymer material.

q2
8. (amended) A device according to any one of Claims 1, wherein the areas of weakness extend as lines of weakness between the areas of the substrate carrying the semiconductor devices.

Sub C1
9. (amended) A device according to any one of Claims 1, wherein the discrete areas of the substrate carrying the semiconductor devices are thicker than the remaining areas of substrate.

Sub C2
10. (amended) A device according to claim 1, wherein the semiconductor devices each comprise a semiconductor film formed into an island.

Sub C3
11. (amended) A device according to claim 1, wherein the semiconductor devices comprises thin film transistors.

Sub C4
12. (amended) A device according to claim 1, wherein the device comprises an active matrix display devices having an array of display pixels and in which each semiconductor device is connected to a respective pixel electrode carried on the substrate.